JAN D & TOTA STEEL

Substitute for form 1449A/PTO

## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known					
Application Number	10/723,526				
Filing Date	November 25, 2003				
First Named Inventor	Hokyun Ahn				
Art Unit	2411				
Examiner Name	HUNG VU				
Attorney Docket Number	2013P134				

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Examiner tritials*	Cite No.1	Document Number  Number - Kind Code <sup>2</sup> (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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	140.	Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (if known)		Applicant of Cited Document	or Relevant Figures Appear	
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Examiner	12:00		Date	09/24/04
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<sup>&</sup>quot;Examiner: Initial if reference considered, whether or not cliation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Teylor & Zafman (wir) 08/11/2003.

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<sup>&</sup>lt;sup>1</sup>Applicant's unique dilation designation number (optional). <sup>2</sup>See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.

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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet 1 of 2

	Complete if Known					
Application Number	10/723,526					
Filing Date	M/25/03					
First Named Inventor	Hokyun Ahn					
Art Unit	261(					
Examiner Name	HUNG VU					
Attorney Docket Number	2013P134					

	U.S. PATENT DOCUMENTS								
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Examiner Signature	HUNG	VU	Date Considered	09/24/04	
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INFORMATION DISCLOSURE		Application Number	10/723,526	_					
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STATE	STATEMENT BY APPLICANT			First Named Inventor	Hokyun Ahn				
	(use as many sheets as necessary)		Art Unit	2811					
	,			Examiner Name	HUNG UU				
Sheet	2	of	2	Attorney Docket Number	2013P134				

NON PATENT LITERATURE DOCUMENTS							
Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²					
	D. Fanning, L. Witkowski, J. Stidham, HQ. Tserng, M. Muir and P. Saunier, Dielectrically defined optical T-gate for high power GaAs pHEMTs, Tri-Quint Semiconductor Texas, GaAs Mantech Conference, April 8-11, 2002, San Diego, California.						
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	Cite No.1	Cite No. 1  Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(e), publisher, dity and/or country where published.  D. Fanning, L. Witkowski, J. Stidham, HQ. Tserng, M. Muir and P. Saunier, Dielectrically defined optical T-gate for high power GaAs pHEMTs, Tri-Quint Semiconductor Texas, GaAs Mantech Conference, April 8-11, 2002, San Diego, California.					

	Examiner Signature	HUNG	NU	Date Considered		09/	24/	04
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